# NSN 5962-01-189-5329

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# **Body Length:**

Between 1.180 inches and 1.220 inches

# Body Width:

Between 0.580 inches and 0.610 inches

# **Body Height:**

Between 0.080 inches and 0.120 inches

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **End Application:**

A/f-18-dcn

## **Features Provided:**

Hermetically sealed and programmable and bipolar and w/enable and 3-state output

## **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

14 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## **Time Rating Per Chacteristic:**

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

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